



# Effect of cerium doping on the optical and photocatalytic properties of ZnO nanoflowers

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**Abstract.** Photocatalytic performances of the synthesized cerium doped (Ce-doped) ZnO nanoflowers are reported in this work. A microwave-assisted sol–gel method is adopted for the synthesis of the nanomaterial and its structural and morphological features are characterized. While doping, the Ce<sup>3+</sup> ions occupy the sites of Zn<sup>2+</sup> ions in the hexagonal ZnO lattice, which is investigated by means of X-ray diffraction studies and energy dispersive X-ray analysis. At higher Ce<sup>3+</sup> concentrations, ultraviolet (UV) light absorption is quite high as evidenced by the UV–Vis absorption spectra. The photoluminescence study demonstrates higher oxygen vacancy and zinc interstitials for the Ce-doped ZnO compared to the undoped ZnO. Ce-doping improves the electrical properties of the sample as well. Finally, it is established that the Ce-doped ZnO nanoflower is highly efficient in UV degrading the methylene blue organic dye.

**Keywords.** Semiconductor; nanoflowers; photoluminescence; defects; microwave-assisted sol–gel method.

## 1. Introduction

Organic dyes are one of the major constituents in several industries like textiles, optoelectronics, food and cosmetics. The exposure of organic waste effluents from industries can greatly affect the environment and its removal is often challenging. In general, chemical coagulation, precipitation, adsorption and membrane filtration techniques are applied for dye removal, particularly from textile wastes [1]. However, most of these methods involve transferring organic compounds from one phase to another and require additional treatments. Nanotechnology has come out as a possible solution for these problems by extending its significance in saving the environment through biodegradation [2,3], recycling [4,5], corrosion inhibition [6,7] and industrial waste management [8]. Recently, nanoparticles as semiconductor-based photocatalysts have been reported for the removal of organic dyes, with their sizes influencing the luminescent and photocatalytic performances [9,10]. Among various metal oxides, the wide band gap and large exciton binding energy make zinc oxide (ZnO) a good candidate for photocatalysis. Moreover, its photosensitivity and chemical stability are quite high [11]. However, the photocatalytic activity of this semiconductor can be further enhanced by many methods such as doping with other metal ions, through which the electron–hole (e<sup>-</sup>/h<sup>+</sup>) recombination rate can be decreased as well [12,13]. The reduction in the rate of the e<sup>-</sup>/h<sup>+</sup> recombination and higher photocatalytic activity by doping are mainly attributed

to the occupancy of dopant ions in the ZnO lattice creating more surface defects [14]. The optical properties of ZnO are enhanced when rare earth metals are doped into it, making the nanomaterial applicable in numerous areas such as biosensors, light emitting diodes, spintronics and photocatalysts. The ultraviolet (UV) absorption and photoluminescence (PL) properties become pronounced by the influence of cerium (Ce)-doping on ZnO due to the enhancement in charge carriers [15–17]. Ln (La<sup>3+</sup>, Nd<sup>3+</sup> or Sm<sup>3+</sup>) doped ZnO synthesized by the polyacrylamide–gel method reported an enhancement in the photocatalytic activity [18]. The photocatalytic activity of ZnO nanoparticles was also enhanced by the addition of lanthanum and yttrium ions [19,20]. Out of the several studies practised on the rare earth metal ion doping on ZnO nanoparticles, doping with the cerium ion has evoked considerable interest because of its promising applications in high-power lasers, light-emitting phosphors and diodes [21–23].

Many methods, such as sol–gel, thermal decomposition, pulsed laser deposition, as well as hydrothermal and chemical reduction, are employed for the synthesis of metal oxide nanoparticles. Among these methods, the microwave-assisted sol–gel method is reported to be a simple and low-cost process compared to conventional heating methods [24–30], since the microwave penetration depth is high and uniform throughout the material [31,32]. We have adopted this simple way of nanoparticle synthesis in the current study to synthesize Ce-doped ZnO nanomaterials. The prepared nanoparticles are well characterized and the influence of Ce-doped ZnO

nanoflowers on the photocatalytic degradation (PCD) of organic dye is investigated in detail, and a plausible explanation has been provided to explain their catalytic activity.

## 2. Experimental

### 2.1 Preparation of photocatalysts

Ce-doped ZnO nanomaterials were synthesized by the previously reported microwave-assisted sol–gel method [33]. The reagents used were obtained from Sigma Aldrich, and were used as such. For the preparation, specific amounts of  $\text{Zn}(\text{CH}_3\text{COO})_2 \cdot 2\text{H}_2\text{O}$  and cerium(III) chloride heptahydrate ( $\text{Ce}(\text{Cl})_3 \cdot 7\text{H}_2\text{O}$ ) were dissolved in a solution containing 0.5 g polyvinylpyrrolidone, 3 ml monoethanolamine and 47 ml deionized water. After continuous stirring on a magnetic stirrer, the whole solution in an autoclave was subjected to irradiation with a microwave power of 300 W [33]. The final suspension obtained after a specific period of irradiation was filtered, washed, dried and calcined for 2 h at 400°C to obtain Ce-doped ZnO. The whole process was repeated by changing the precursor concentration so that Ce-doped ZnO with different molar ratios (3, 6, 9 and 12 mol%) was prepared. To compare the specific properties of Ce-doped ZnO with those of undoped ZnO, the latter was also synthesized following the same procedure.

### 2.2 Characterization techniques

Both ZnO and Ce-doped ZnO samples were analysed using a PANalytical model X'PERT-PRO X-ray powder diffractometer (XRD) equipped with  $\text{CuK}\alpha$  radiation with a wavelength of 1.5418 Å. Morphologies were examined using the Hitachi S-4200 field emission scanning electron microscope (FE-SEM) at 15 kV and the JEOL JEM 2011 transmission electron microscope (TEM) at 200 kV. The specific surface areas of the nanomaterials were checked from nitrogen absorption data obtained from the micromeritics ASAP 2020 V3.05H and porosity analyser based on the Brunauer–Emmett–Teller (BET) method. The electrical properties of the pelletized samples were further analysed by an AC impedance analyser containing a computer interfaced phase sensitive multimeter (PSM 1735). Band gap analysis was performed using a Shimadzu UV–Vis spectrophotometer (UV-2550) fitted with a diffuse reflectance spectra (DRS) accessory and the PL studies were performed by Perkin Elmer: FLW in a lab LS 55 spectrofluorometer. A Shimadzu UV–Visible double beam spectrophotometer (UV-1700) was used to check the dye concentration. The physico-chemical properties of the model pollutant, methylene blue (MB) dye, is shown in table 1.

The photocatalytic reaction was performed by the reported procedure [33]. For this, the dye mixed with the nanoparticles was first kept in the dark to achieve the adsorption–desorption equilibrium and thereafter kept in UV irradiation (254 nm)

**Table 1.** Details of MB dye.

Dye	Methylene blue
Characteristics	Cationic, water soluble
Formula	$\text{C}_{16}\text{H}_{18}\text{N}_3\text{SCl}$
$\lambda_{\text{max}}$	665 nm
Applications	Redox indicator, sulphide analysis, peroxide generator

within a Heber multi-lamp photoreactor. The dye concentration was monitored at regular intervals of time using the UV–Vis spectrophotometer. A decrease in concentration of the dye was marked by a decrease in the absorption peak intensity at 660 nm. The PCD efficiency ( $\eta$ ) was also calculated using equation (1):

$$\eta = \frac{(C_i - C_t)}{C_i} \times 100, \quad (1)$$

where  $C_i$  is the initial dye concentration and  $C_t$  the final concentration after  $t$  min.

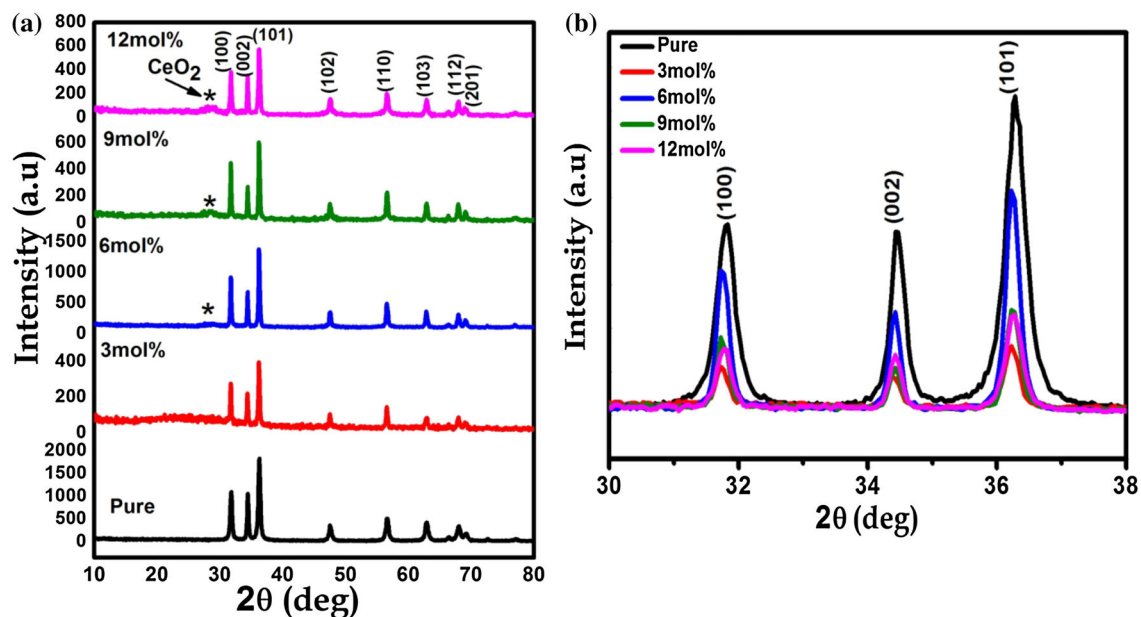
## 3. Results and discussion

### 3.1 Crystallinity studies

XRD patterns of Ce-doped ZnO are compared with those of undoped ZnO as shown in figure 1. The diffraction peaks due to the undoped ZnO observed at 31.67, 34.41, 36.26, 47.64, 56.62, 62.87, 67.86 and 69.10°, respectively, correspond to the (100), (002), (101), (102), (110), (103), (112) and (201) hexagonal planes (JCPDS card no: 79-0208). From figure 1a, no diffraction peaks are observed for the cerium compounds up to an addition of 3 mol%. But at a higher cerium concentration, a new peak at  $2\theta$ , 28.67° related to  $\text{CeO}_2$  appears in the spectrum (JCPDS card no: 81-0792). This corresponds to the (111) plane for the  $\text{CeO}_2$  crystalline structure and shows the formation of the secondary phase of  $\text{CeO}_2$  at a higher concentration of  $\text{Ce}^{3+}$  ions. This is because of the limited  $\text{Ce}^{3+}$  ion solubility in the host ZnO spinel lattice [34]. Figure 1b shows the effect of Ce-doping on ZnO crystallinity. Diffraction peaks corresponding to (100), (002) and (101) planes for Ce-doped ZnO samples are slightly shifted to lower angles compared to the undoped ZnO. In addition, the intensity of the diffraction peaks is decreased, confirming the presence of  $\text{Ce}^{3+}$  ions in the ZnO lattice.

The average crystallite size can be calculated using Scherrer equation (2) [35]:

$$D = \frac{0.9\lambda}{\beta \cos \theta}, \quad (2)$$



**Figure 1.** (a) XRD spectra and (b) (100), (002) and (101) peak positions for the ZnO and Ce-doped ZnO nanostructures.

**Table 2.** Calculated lattice parameters, size of the crystallites and band gap of the ZnO and Ce-doped ZnO nanostructures.

Samples	Lattice parameters			Debye–Scherrer crystallite size (nm)	Band gap (eV)
	<i>a</i> (Å)	<i>c</i> (Å)	<i>c/a</i> ratio		
ZnO	3.249	5.204	1.601	22	3.15
3 mol% Ce–ZnO	3.252	5.209	1.601	34	3.12
6 mol% Ce–ZnO	3.253	5.210	1.601	33	3.10
9 mol% Ce–ZnO	3.253	5.211	1.601	30	3.08
12 mol% Ce–ZnO	3.255	5.214	1.601	22	3.03

where  $D$  represents the average crystallite size,  $\lambda$  is the wavelength of X-rays;  $\beta$  is the full width at half maximum and  $\theta$  is the scattering angle.

According to Bragg's law, the lattice constants  $a$  and  $c$  were calculated by the following relation (3) [36]:

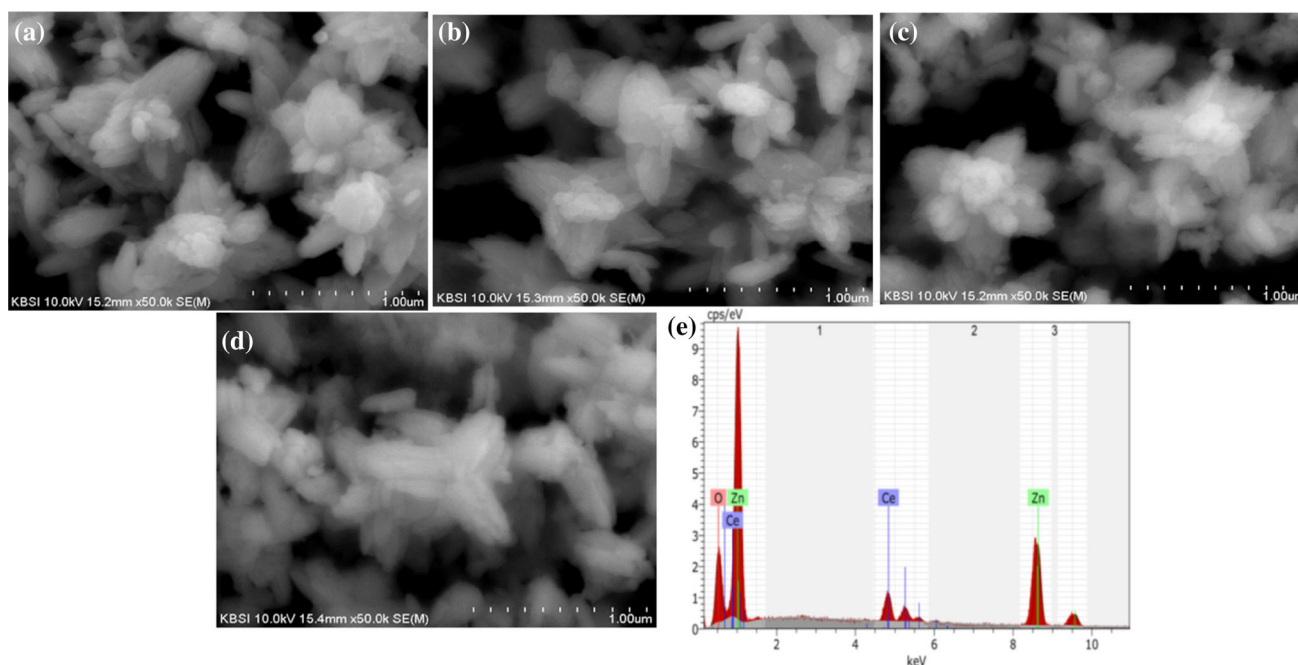
$$\frac{1}{d_{(h,k,l)}^2} = \frac{4}{3} \left( \frac{h^2 + hk + k^2}{a^2} \right) + \frac{l^2}{c^2}. \quad (3)$$

The calculated lattice parameters and crystallite sizes of the nanoparticles are shown in table 2. It is clear that the crystallite size of ZnO increases from 22 to 34 nm when it is doped with 3 mol% cerium, and further doping at 6, 9 and 12 mol% decreases the crystallite size. It is well known that the crystallite size contributions to XRD line broadening are independent of each other. The decreased crystallite size can be explained by the interruption in movement of the grain boundaries by the Zener pinning effect [37]. Here,

the presence of Ce ions in ZnO prevents the growth of crystal grains and slows down the motion of the grain boundary. This causes a retarding force on the boundaries such that if this force is more than the driving force for grain growth, the particles cannot grow any longer [38,39]. The larger crystallite size at 3 mol% Ce-doping can be due to the Ostwald ripening effect, in which relatively larger particles grow at the expense of the smaller ones [40]. Based on Vegard's law, the lattice parameters show an increase, corresponding linearly to the  $\text{Ce}^{3+}$  concentration [41]. Also, the ionic radius of  $\text{Zn}^{2+}$  (0.74 Å) is smaller than that of  $\text{Ce}^{3+}$  ions (1.03 Å). The observed lattice parameter values for both ZnO and Ce-doped ZnO are in good agreement with the JCPDS card no: 79-0208.

### 3.2 Morphology studies

Figure 2 illustrates the SEM images for the Ce-doped ZnO and confirms its flower like morphology. Similar morphologies are observed for the undoped ZnO as well [33,42]. These



**Figure 2.** SEM images of Ce-doped ZnO at various mol%: (a) 3 mol%, (b) 6 mol%, (c) 9 mol%, (d) 12 mol% and (e) EDX spectrum of 12 mol% Ce-doped ZnO.

pieces of evidence show that the  $\text{Ce}^{3+}$  ion incorporation has not disturbed the ZnO lattice.

The flower like morphology is mainly attributed to the addition of monoethanolamine which serves as an intermediate complex. The elemental analysis (EDX) spectrum for the 12 mol% Ce-doped ZnO sample is illustrated in figure 2e. This spectrum indicates the presence of Zn, Ce and O atoms as the major chemical components in the Ce-doped ZnO. This observation indicated the absence of any impurity in the Ce-doped ZnO nanoflowers.

Further information about the morphology is explored by means of TEM images shown in figure 3. The undoped ZnO and all Ce-doped ZnO samples exhibit a nanoflower like morphology [42]. This illustrates that the ZnO lattice is not affected by the  $\text{Ce}^{3+}$  ions.

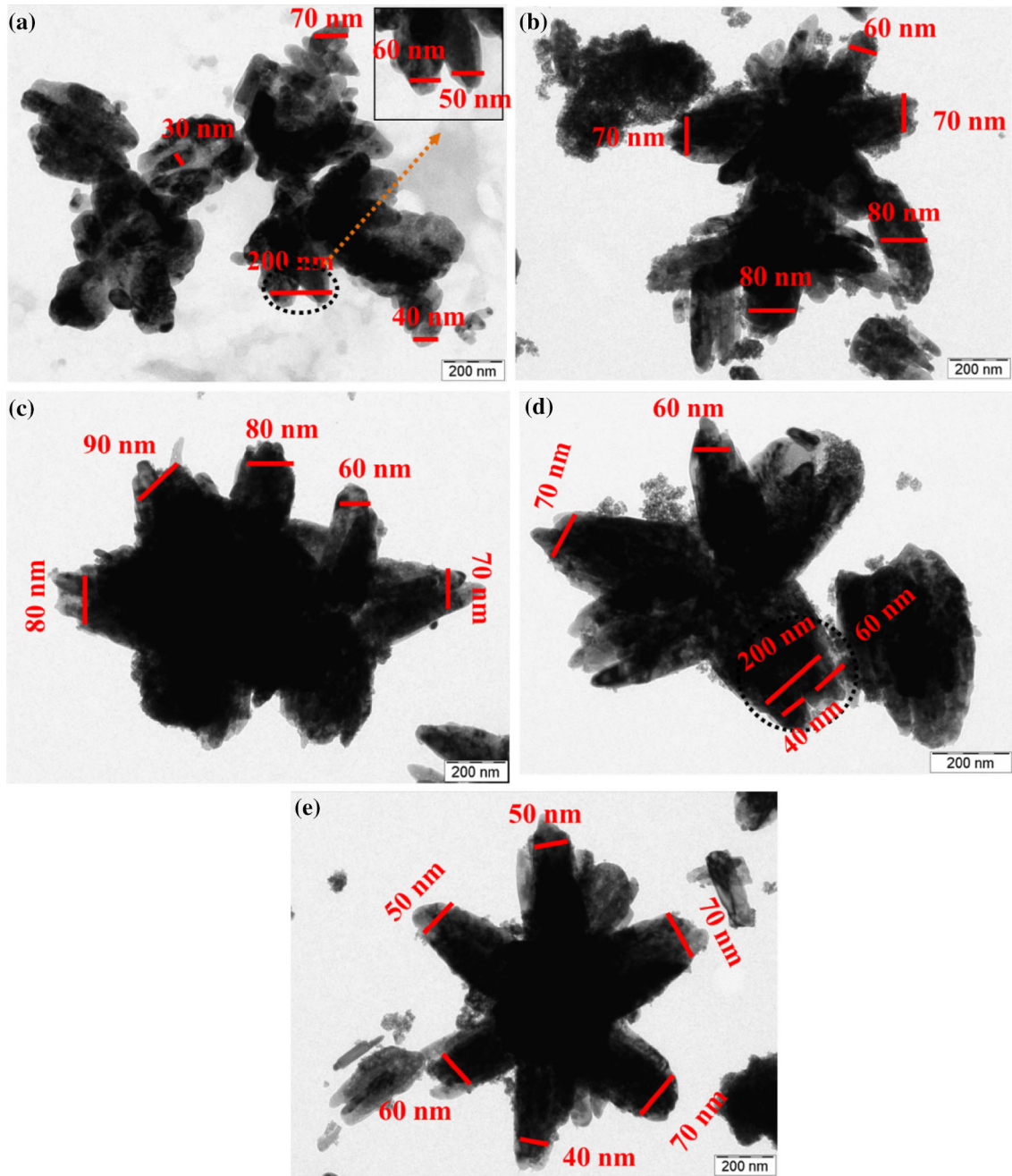
Parameters such as the average diameter of the nanorods, shape and number of petals of the pure ZnO and Ce-doped ZnO nanoflowers are compared in table 3. It is notable that the average diameter enhances first and then decreases with the percentage of cerium doping. In addition, the undoped ZnO shows an agglomerated flower like morphology, whereas with cerium doping, the petals for flowers begin to form.

The high-resolution transmission electron microscopy (HRTEM) pattern (figure 4a) representing nanocrystalline structures of the 12 mol% Ce-doped ZnO shows the pinning of two domains having two different orientations, i.e., the (002) plane with a  $d$ -spacing of 2.6 Å and the (111) plane with a  $d$ -spacing of 3.1 Å due to the effect of Ce-dopant concentration on the ZnO lattice, whereas in the undoped case the (002) planes were present with inter-planar  $d$ -spacing, 2.6 Å

[42]. The selected area electron diffraction patterns (SAED) for the 12 mol% Ce-doped ZnO (figure 4b) also confirms the crystallinity of the sample.

In order to explain the formation of flower shaped Ce-doped ZnO nanostructures, a possible formation mechanism is proposed as shown in figure 5. Monoethanolamine plays an important role in the growth of Ce-doped ZnO nanostructures. This precursor initiates the formation of many amorphous seed nuclei within the nanostructure, which further grow to longer rods. In other words, the growth is by the well-known Ostwald ripening effect in which the growth of a large particle occurs at the expense of smaller ones. This mechanism occurs quite easily when dispersed in a solvent, and the various sub-units of grown nanoparticles are interconnected by the orientation attachment process to derive the nanoflower architecture [43].

To investigate the specific surface area and porosity of the undoped-ZnO and Ce-doped ZnO samples, the  $\text{N}_2$  adsorption–desorption isotherm measurements are conducted. The BET surface areas of undoped-ZnO and 12 mol% Ce-doped ZnO, respectively, give the values 6.6168 and 12.03  $\text{m}^2 \text{g}^{-1}$ . These specific surface area values are comparable. In addition, the specific pore volume of the 12 mol% Ce-doped ZnO sample is 0.023  $\text{cm}^3 \text{g}^{-1}$ , as revealed in the Barrett–Joyner–Halenda plot (inset figure 6). Figure 6 shows the representative  $\text{N}_2$  adsorption–desorption isotherms of ZnO and 12 mol% Ce-doped ZnO samples. It showed a type II isotherm with a large type hysteresis loop [44]. The formation of the hysteresis loop in the adsorption–desorption isotherm of the Ce-doped sample indicates its non-porous nature. The



**Figure 3.** (a) TEM image of pure ZnO and (b–e) 3, 6, 9, 12 mol% Ce-doped ZnO samples.

**Table 3.** Comparison of average diameter, shape and number of petals.

Sample	Average diameter (nm)	Shape	Number of petals
ZnO	30–70	Agglomerated flowers	2
3 mol% Ce–ZnO	60–80	Agglomerated flowers	6
6 mol% Ce–ZnO	60–90	Flower shape	5
9 mol% Ce–ZnO	40–70	Flower shape	4
12 mol% Ce–ZnO	40–70	Flower shape	6

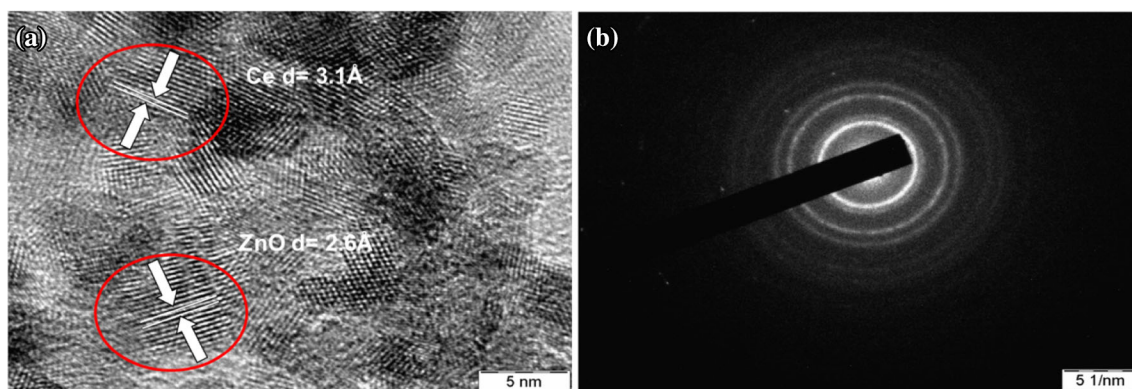


Figure 4. (a) HRTEM image and (b) SAED pattern of 12 mol% of Ce-doped ZnO.

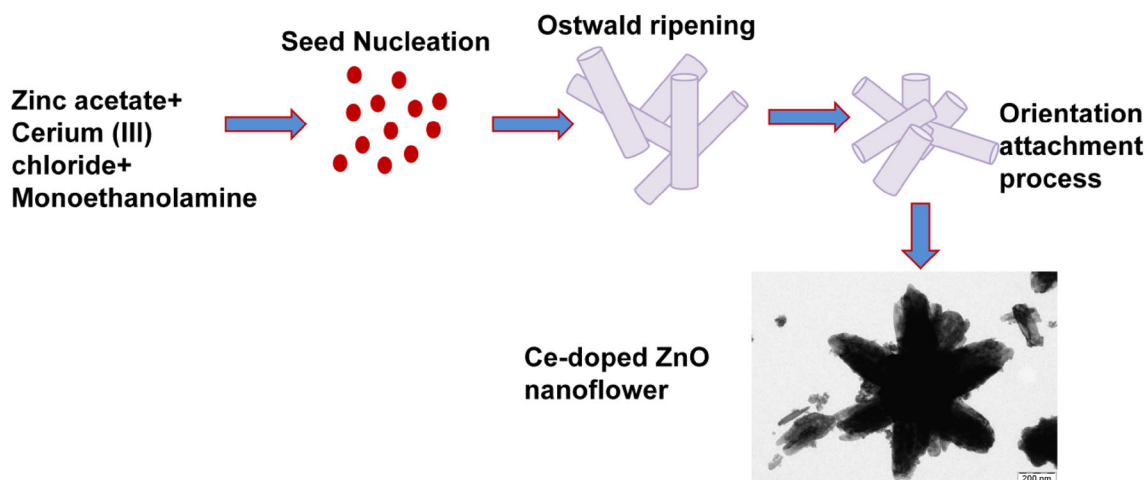


Figure 5. Possible formation mechanism of flower-like Ce-doped ZnO sample.

results reveal the influence of  $\text{Ce}^{3+}$  doping in enlarging the surface area.

### 3.3 Electrical property investigation

Impedance spectroscopy analysis is a powerful technique for determining the electrical properties of the samples. Figure 7a shows the Nyquist plots and figure 7b shows the variation of the dielectric constant with frequency for the undoped-ZnO and Ce-doped ZnO samples.

All the samples exhibit semicircular curves in a higher frequency region (figure 7a). This indicates the presence of  $\text{Ce}^{3+}$  ions in the ZnO lattice. The semicircle at high frequencies is related to the interfacial charge transfer resistance. The semicircle or electron transfer resistance has decreased for the Ce-doped ZnO, which suggests the incorporation of  $\text{Ce}^{3+}$  ions into the ZnO lattice thus making the process of electron transfer easier [45].

Figure 7b shows the frequency dependence of the dielectric constant  $\epsilon'$  at room temperature for the ZnO and Ce-doped

ZnO. From the spectra, it can be seen that the dielectric constants are high in the low frequency region, whereas those in the higher frequency side decrease. It is evident that the dielectric constant is greater for the doped samples compared to the undoped-ZnO. This is because of the increase in dipole moment of the Ce-doped systems. The better dielectric properties support the applicability of Ce-doped ZnO in charge storage devices and in photocatalysis [46].

### 3.4 UV-Vis DRS analysis

The optical parameters are very important to verify how the Ce doping on ZnO affects their absorption properties. Figure 8a shows the UV-Vis DRS of ZnO and Ce-doped ZnO nanoflowers. The optical absorption is recorded in the range of 300–800 nm by the UV-Vis spectrophotometer.

A strong absorption band is observed at 361 nm. It is interesting to note that the absorption of ZnO peaks increases considerably above this region and in comparison with that of undoped-ZnO, the optical absorption edges of the Ce-doped ZnO samples are shifted towards the longer wavelength

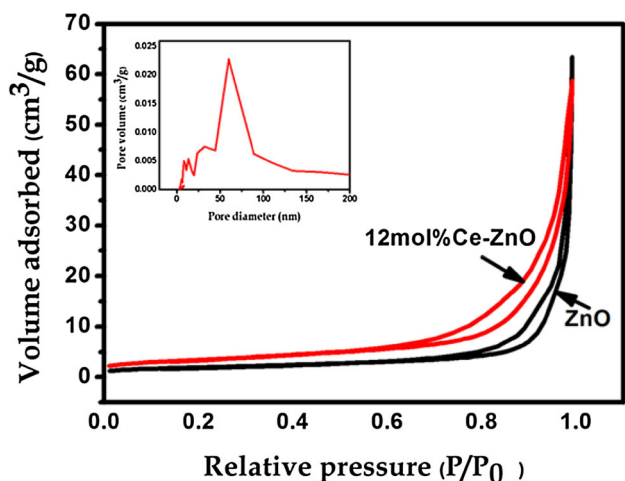


Figure 6. BET isotherms of ZnO and 12 mol% Ce-doped ZnO nanoflower.

region. This red shift is attributed to the presence of  $Ce^{3+}$  ions, and charge transfer transitions occurring between the lanthanide ‘f’ electrons and the conduction band/valence band (CB/VB) of ZnO.

The band gap of the nanomaterials is calculated by equation (4)

$$\alpha h\nu = A (h\nu - E_g)^n, \tag{4}$$

where  $\alpha$  is the absorption coefficient. Values of ‘n’ are different for different types of transitions. It is equal to 1/2 for the allowed direct transition and 2 for the allowed indirect transition. But n takes the values of 3/2 and 3 for the direct and indirect forbidden transitions, respectively. ‘A’ is a temperature independent constant and it corresponds to the band tailing. Tauc’s plots (figure 8b) are drawn as the variation of  $(\alpha h\nu)^2$  vs. photon energy ( $h\nu$ ) in which the X-intercept of the

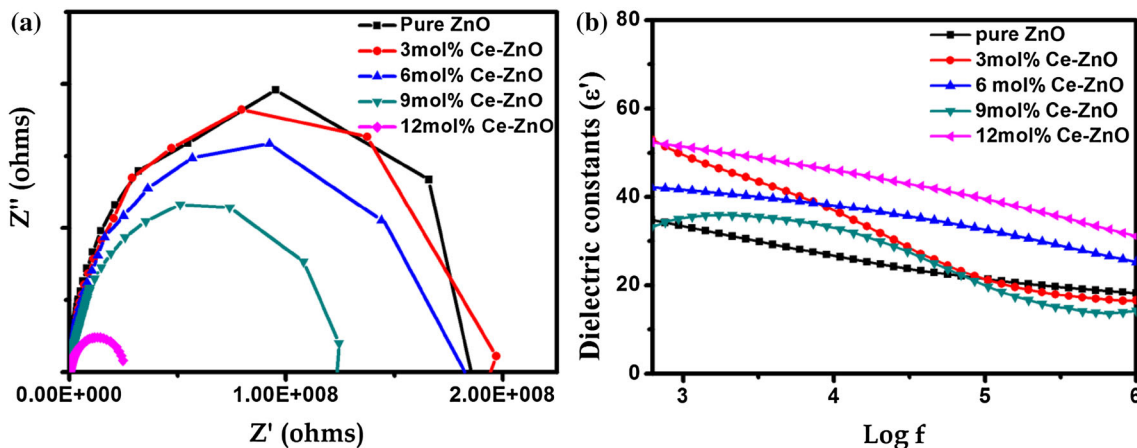


Figure 7. (a) Nyquist plots and (b) dielectric constant vs. log f plots of ZnO and Ce-doped ZnO samples.

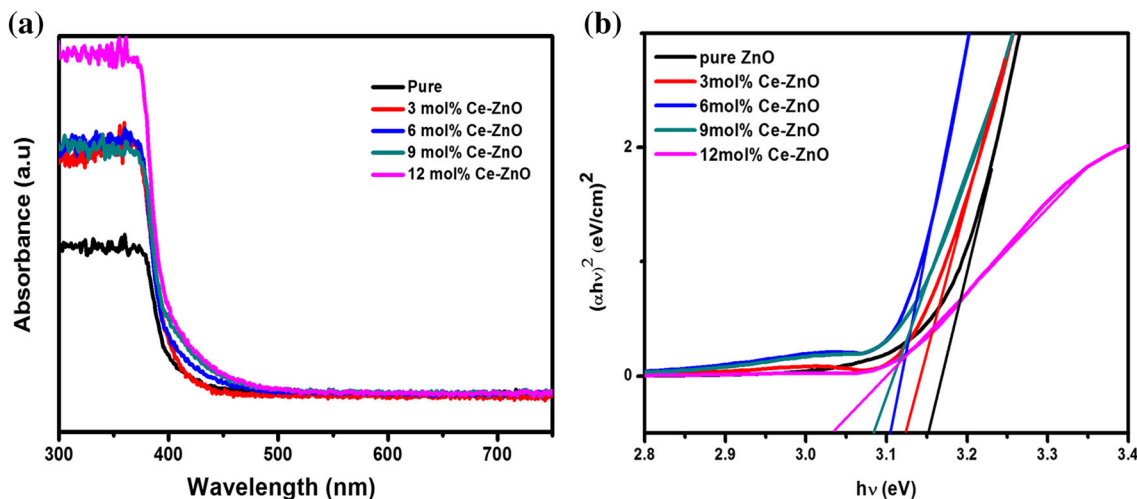


Figure 8. Variation of (a) absorbance with wavelength and (b)  $(\alpha h\nu)^2$  with  $h\nu$  for the ZnO and Ce-doped ZnO.

tangent marks the direct band gap ( $E_g$ ) of the photocatalysts. The  $E_g$  values are shown in table 2. The  $E_g$  value shifts to the shorter or longer wavelength sides depending on the size and the dopant ions in different forms. It can be seen that the  $E_g$  value decreases as the dopant concentration increases. Therefore, the decrease in the  $E_g$  value of the samples can be attributed to the presence of the  $Ce_2O_3$  secondary phase. The red shift of the photocatalyst can also be ascribed to the charge transfer between the ZnO VB or CB and the cerium ion in the 4f level [47].

During Ce doping, the photoelectron trap centres are formed and these are accompanied by the formation of defects. Liu *et al* [48] proposed that the red shift of the absorption edges accounts for a large number of surface defect states. These defect states help to enhance the photocatalytic behaviour of the synthesized Ce-doped ZnO materials.

The dopant induced red shift and increased absorption intensity can be attributed to the increased rate of the electron-hole pair formation on the photocatalyst surface. This electron-hole recombination results in higher photocatalytic activity of the photocatalysts [49].

### 3.5 PL studies

The PL spectra of ZnO and Ce-doped ZnO samples at the excitation wavelength of 325 nm are represented in figure 9.

Generally, PL emission for metal oxide nanostructures possesses a near-band edge (NBE) UV emission and deep level (DL) defect associated with the visible emission that are closely related to the surface states, oxygen vacancies and defects [50]. As shown in figure 9, a strong UV band gap emission takes place at 391 nm due to the radiative recombination of the VB hole and the excited CB electron. Visible or deep trap state emissions (411, 444, 485, 491 and 521 nm) commonly defined as the electron-hole pair recombination from localized states with energy levels deep in the band gap are lower energy emissions [51] and are caused by

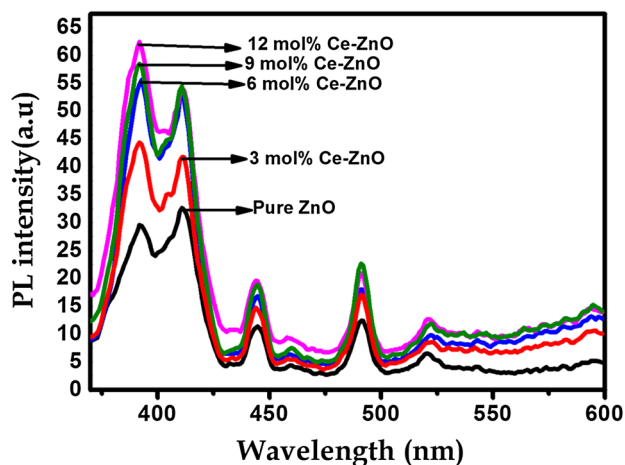


Figure 9. PL spectra of ZnO and Ce-doped ZnO nanostructures.

different intrinsic defects in ZnO, such as ionic vacancy (oxygen/zinc), interstitial ions and antisite oxygen [52]. While the violet emission (411 nm) is due to the surface zinc vacancy [53], the blue emission (444 and 491 nm) peak comes from the simply trapped electrons at the interface lying within the depletion regions of ZnO grain boundaries [54]. The green emission (521 nm) comes from the energy gap between the levels of oxygen vacancy and the valence band [52]. The Ce-doped ZnO nanostructures show high PL intensities compared to ZnO indicating higher oxygen vacancies and other defects in the former. It is also due to the high separation rate of photo-induced charge carriers and higher electron-hole separation [55]. This will help to enhance the photocatalytic activity.

### 3.6 Photocatalytic activity

The heterocyclic and aromatic compound, MB dye, is 3,7-bis(dimethylamine)-phenothiazine-5-iumchloride ( $C_{16}H_{18}N_3$  SCl). The MB powder is soluble in water and it is mainly used for applications related to environmental science and chemistry [56]. Here, the degradation process of MB dye using undoped-ZnO and Ce-doped ZnO was investigated under UV light irradiation.

Figure 10 shows the influence of time on the MB dye degradation in the presence of ZnO and Ce-doped ZnO systems under UV light irradiation. The percentage of dye degradation is calculated based on the UV absorbance values as follows:

$$D (\%) = \frac{(A_0 - A)}{t}, \quad (5)$$

where  $D$  is the dye degradation percentage,  $A_0$  is the initial absorbance and  $A$  is the absorbance at time  $t$ . The characteristic UV absorption peak of MB at 665 nm decreases in intensity with an increase in irradiation time, and this is clear from the increased percentage of dye removal with time. Compared to ZnO nanoparticles, the Ce-doped ZnO nanoparticles show

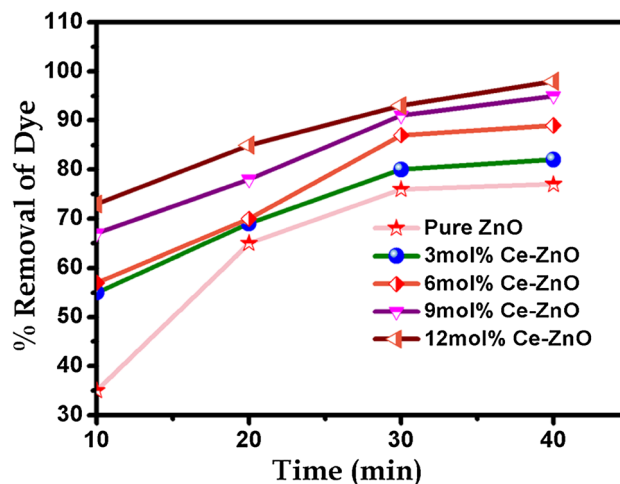


Figure 10. Variation in the degradation of dye with time.

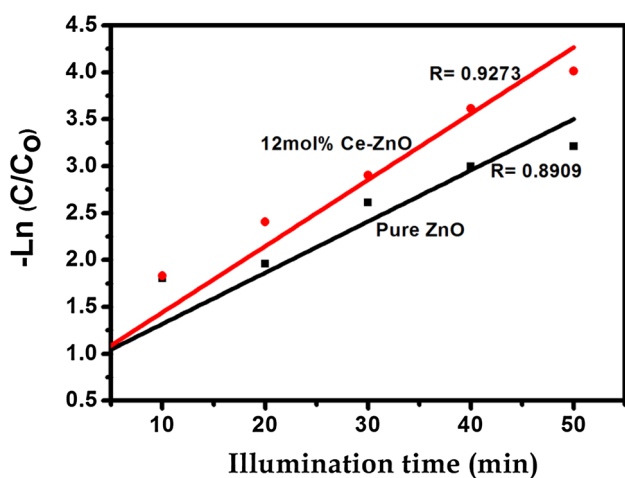


better photocatalytic performances. A close look at figure 10 illustrates that the 12 mol% Ce-doped ZnO nanoparticles drastically decrease the absorbance of MB dye with an increase of irradiation time. This sample exhibits the best PCD (94%) in 50 min.

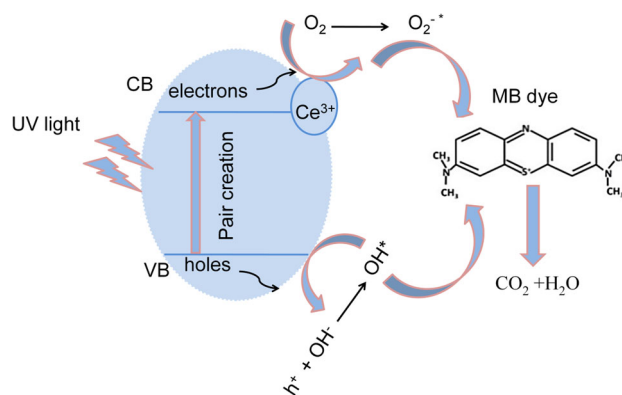
In metal–oxide semiconductors, the photocatalytic activity typically depends on the morphologies [57], particle size [58] and surface properties [59]. In the present system, the higher photodegradation efficiency of the Ce-doped ZnO is explained on the basis of surface defects. Both the undoped and doped nanoparticles show similar morphologies and particle sizes; however, the particle sizes of the former are smaller than those of the latter. Moreover, the higher surface defects of the doped samples are clearly shown in figure 9, which confirms the enhanced photocatalytic activity. This is also explained based on the electron–hole pair recombination ratios. The defects on the surface of the catalyst create numerous photogenerated electron–hole pairs. More surface defects, such as oxygen vacancies and zinc interstitials, were attributed to the lower recombination between photo-generated electrons and holes with oxygen vacancies serving as electron traps [60]. This results in better dye degradation upon optimum cerium ion doping in the ZnO lattice.

**3.6a Decolouration kinetics:** Figure 11 represents the photocatalytic dye degradation that obeys the pseudo-first order kinetics. The regression curve of the natural logarithm of  $C_0/C_t$  vs. illumination time gives a straight line. This plot suggests that the photo-decolouration reaction approximately follows the pseudo-first order kinetics as represented by equation (6)

$$\ln \left( \frac{C_0}{C_t} \right) = Kt, \quad (6)$$



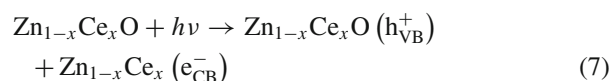
**Figure 11.** Pseudo-first order kinetics of the degradation of MB using undoped-ZnO and 12 mol% of Ce-doped ZnO under UV light.



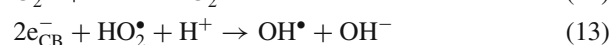
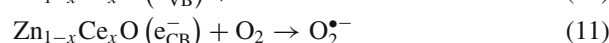
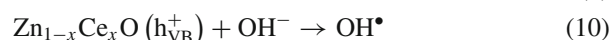
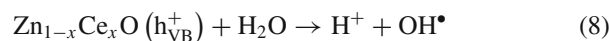
**Figure 12.** Formation of hydroxyl and superoxide radicals under UV light irradiation.

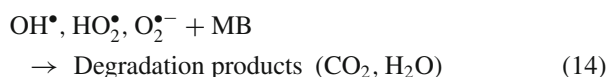
where  $C_0$  is the initial concentration of the dye and  $C_t$  is the concentrations at various time intervals.  $K$  is the pseudo-first order constant for degradation of the dye and  $t$  is the irradiation time [61].

**3.6b The photo-catalytic degradation mechanism:** Figure 12 illustrates the plausible reaction mechanism proposed for the photo-degradation of dye by the Ce-doped ZnO sample. The generation of electron–hole ( $e^-h^+$ ) pairs between the VB and CB of Ce-incorporated ZnO provides the driving force for the  $e^-/h^+$  movement, in turn a better degradation activity of MB dye. ZnO particles upon irradiation with photons cause for the excitation of an  $e^-$  from its VB to the CB leaving behind a positively charged  $h^+$  in the VB [33]. Thus, the generated charge carriers can recombine on the surface of Ce-doped ZnO, serving as oxidizing and redox sources as represented by the electron donor/acceptor in equation (7).



The VB  $h^+$  reacts with the chemisorbed  $\text{H}_2\text{O}$  molecules to form reactive species such as hydroxyl ( $\text{OH}^\bullet$ ) radicals. Likewise, CB  $e^-$  results in the formation of superoxide ( $\text{O}_2^\bullet$ ) radicals by the trapping of electrons by oxygen atom. The generated  $\text{O}_2^\bullet$  then further combines with  $\text{H}^+$  to produce  $\text{HO}_2^\bullet$ , which can react with the trapped electrons to generate  $\text{OH}^\bullet$  radicals [51]. The highly reactive hydroxyl radicals then attack organic compounds. Finally, the degradation product is obtained as per equations (8–14).





#### 4. Conclusion

Ce-Doped ZnO nanoflowers were prepared by the microwave-assisted sol-gel method. The structural characterization of the samples by XRD showed the hexagonal wurtzite structure and also Ce-incorporation deteriorates the crystallinity. The energy dispersive X-ray spectra confirmed the elemental compositions in the Ce-doped ZnO system. The optical band gap of the Ce-doped ZnO showed a red shift when compared with the undoped-ZnO, which can be attributed to a charge transfer transition between the lanthanide 'f' electrons of Ce and the CB or VB of the host ZnO. PL measurements showed NBE UV emission and DL visible emission, and these emissions are closely related to the surface states, oxygen vacancies and defects. It is confirmed that the Ce dopant has a significant effect on structural, optical and photocatalytic properties. The PCD efficiency increased with an increase of Ce-dopant concentration, which indicated the applicability of Ce-doped ZnO in photocatalysis.

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